



SINGLE LINE CAN/LIN BUS PROTECTOR

Product Summary

V _{BR (Min)}	I _{PP (Max)}	I _{R (Max)}
25.7V	8A	100nA

Description and Applications

This new generation TVS is designed to meet the stringent requirements of Automotive Applications and to protect sensitive electronics from the damage due to ESD. The combination of small size and high ESD surge capability makes it ideal to protect LIN and CAN transceiver from ESD, EMI and other harmful transient voltage events for use in:

- Industrial Control Network
- Automotive Networks

Features and Benefits

- 350W Peak Power Dissipation per Line (8/20µs Waveform)
- Provides ESD Protection per IEC 61000-4-2 Standard: Air ±30kV, Contact ±30kV
- 2 Channels of ESD Protection
- Low Channel Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

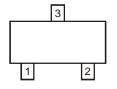
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.009 grams (Approximate)

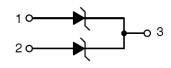
SOT23



Top View



Bottom View



Device Schematic

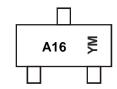
Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DUP1105SOQ-7	Automotive	A16	7	8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



A16 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key

Year	201	7	2018		2019	20	20	2021		2022	2	2023
Code	E		F		G	ŀ	1			J		K
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Power Dissipation	P_{PP}	350	W	8/20µs, per Figure 1
Peak Pulse Current	lpp	8	Α	8/20µs, per Figure 1
ESD Protection – Contact Discharge	V _{ESD_Contact}	±30	kV	IEC 61000-4-2 Standard
ESD Protection – Air Discharge	V_{ESD_Air}	±30	kV	IEC 61000-4-2 Standard

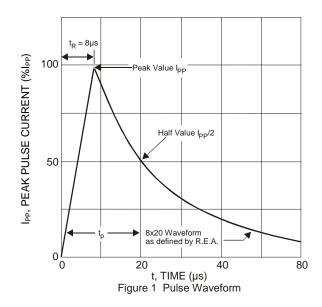
Thermal Characteristics

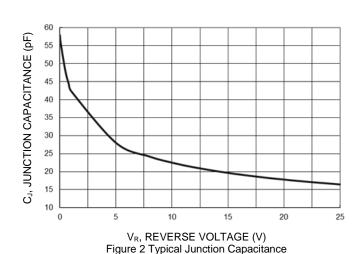
Characteristic	Symbol	Value	Unit
Package Power Dissipation (Note 6)	P _D	300	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ hetaJA}$	417	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Standoff Voltage	V_{RWM}	_	_	24	V	_
Channel Leakage Current (Note 7)	I _{RM}	_	10	100	nA	V _{RWM} = 24V
Clamping Voltage Regitive Transients	.,,	_	_	40	V	$I_{PP} = 5A$, $t_P = 8/20\mu s$, Figure 1
Clamping Voltage, Positive Transients	V _{CL}	_	_	44		$I_{PP} = 8A$, $t_P = 8/20\mu s$, Figure 1
Breakdown Voltage	V _{BR}	25.7	_	32	V	$I_R = 1mA$
Differential Resistance	R _{DIF}	_	0.4	_	Ω	$I_R = 1A$, $t_P = 8/20\mu s$
Channel Input Capacitance	Ст	_	_	60	pF	$V_R = 0V$, $f = 1MHz$

Notes:

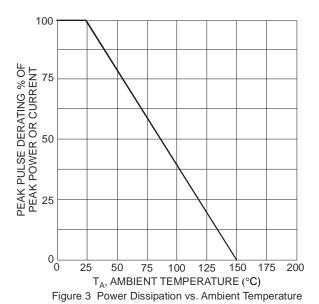




^{6.} Device mounted on FR-4 PCB pad layout (2oz copper) as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.

7. Short duration pulse test used to minimize self-heating effect.





-55°C 1000000 25°C 100000 IR, LEAKAGE CURRENT (nA) 10000 1000 85°<u>.</u>C 150°C 125°C 100 10 0.1 0.01 35 10 15 20 25 30 0 V_R, REVERSE VOLTAGE (V) Figure 4 Typical Reverse Characteristics

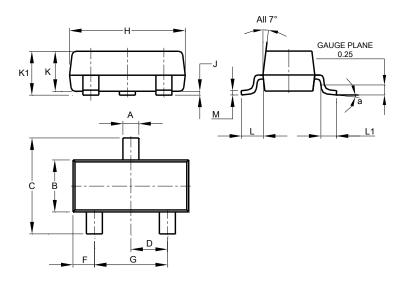
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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

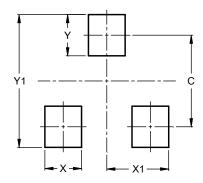


SOT23						
Dim	Min	Max	Тур			
A	0.37	0.51	0.40			
В	1.20	1.40	1.30			
C	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

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Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9